



dRICH SiPM bias distribution

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Bias distribution

Topics of interest

- <u>Topology</u> of the Bias distribution
 - a diagram/schematic illustrating the approach
- <u>Granularity</u> of the Bias supplies
 - how many SiPMs (or groupings of) are to be fed from a single Bias supply channel?
- Bias Channel counts and need for distribution chassis
- Temperature dependencies
 - Bias compensation, measurement and compensation, etc.
- Bias supply/gain <u>stability and noise requirements</u>
- Configuration controls with reference to SiPM serial numbers

dRICH bias voltage distribution

bias voltage to SiPM sensors we have two bias voltages to distribute to SiPM

• HIGH VOLTAGE (Vbias)

- this is the normal operation mode for Physics
- <u>reverse bias</u> to SiPM
- < 55 V
- \circ < 1 μ A / sensor

• ANNEALING VOLTAGE (Vann)

- when doing annealing recovery of radiation damage
- <u>forward bias</u> to SiPM
- <12 V
- o < 150 mA / sensor</p>

dRICH numbers 6 sectors 1248 PDUs 320k SiPMs







The Masterlogic v2

we developed and operated in the dRICH beam test in October 2023 the MasterLogic v2 card (evolution of the MasterLogic v1 card).

the card hosts

- 8 channels made of identical circuits for linear regulation of Vbias from 0 to Vin (80 V max)
- a microcontroller (PIC) for external communication (RS485)
- voltage & current monitor

the MasterLogic v2 card hosts more features that are needed for beam test operations. Some of them will be delegated to the RDO, other might be included or dropped.



The Masterlogic v3 and the patch panel

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- a microcontroller (PIC) for external communication (RS485)
- current monitor?
- something else?

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a future evolution might be a MasterLogic v3 card to plug onto the dRICH readout box patch panel for Vbias and Vann control and distribution (and perhaps more features).



8

Vbias distribution summary table) th is chear th	this this is cheaper than that		custom this is likely cheaper, but more complex	
		↓ 1 main 1 PDU	↓ 1 main 4 PDU	1 main 52 ML3 4 PDU	1 main 208 ML3 4 PDU	
	N _{primary}	1248	312	6	6	
	N _{primary} / sector	208	52	1	1	
	V _{primary} (V)	60	60	60	60	
	I _{primary} (A)	< 1 mA	< 1 mA	250 mA	1 A	
	Granularity	256	1024	1024	256	
	uControl	no	no	yes	yes	

Vbias distribution

the circuit foreseen to allow both normal operation of SiPM (reverse bias) and self-annealing (forward bias) allows to inhibit the Vbias to a granularity of 8 SiPM.

might come at handy in case of troubles with Vbias distribution in a specific SiPM \rightarrow inhibit Vbias in a string of 8 SiPM sensors while the rest of the PDU can still be operated

digital switches (MOSFET) controlled by RDO



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Vann distribution

forward-bias annealing current for each sensor can reach up to 100 mA to keep annealing current low we foresee to forward-bias the SiPM in series of 4 SiPM strings

note: this approach should work but has to be tested to prove its performance



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Summary

two potentially good approaches (both for Vbias and Vann) typically one approach has less primary channels with higher power / current the other approach has more primary channels and lower power / current

	Vbias (option A)	Vbias (option B)	Vann (option A)	Vann (option B)
N _{primary}	6	312	78	624
N _{primary} / sector	1	52	13	104
V _{primary}	60 V	60 V	48 V	48 V
l _{primary}	1 A	1 mA	8 A	1 A
analog grouping voltage regulation	256	1024	4096	32
digital grouping capability to turn OFF	8	8	32	32
T dependence	yes measured and regulated	yes measured and regulated	no	no
stability	< 20 mV	< 20 mV	< 100 mA	< 100 mA
noise ripple	< 3 mVpp	< 3 mVpp	< 100 mVpp	< 100 mVpp

PDU voltage services

the **<u>SiPM grouping</u>** is composed of 4 strings of 8 SiPM each

one <u>SiPM matrix</u> is composed of two SiPM groupings

the <u>dRICH PDU</u> is composed of four SiPM matrices

for each SiPM grouping we foresee the following external services (via RDO)

- 1 V-bias
- 1 CTRL-bias
- 1 V-ann
- 1 CTRL-ann
- 1 GND

This is a total of 5 wires for each SiPM grouping, namely a total of <u>40 wires for</u> <u>one PDU</u>. The 40 wires enter on the RDO from the readout box patch-panel.



PDU voltage services



PDU voltage services

